TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA8258H

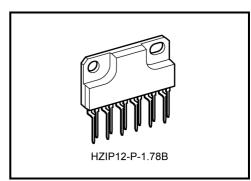
Dual Audio Power Amplifier

The TA8258H is dual audio power amplifier for consumer applications.

This IC provides an output power of 20 watts per channel (at V_{CC} = 37 V, f = 1kHz, THD = 10%, R_L = 8 Ω). It is suitable for power amplifier of music center.

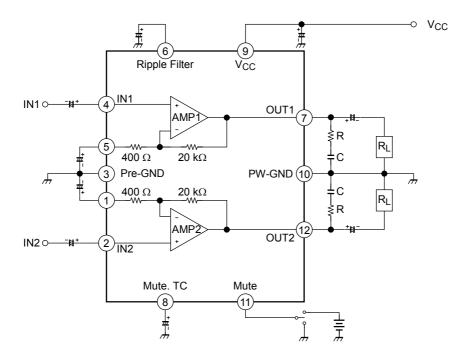
Features

- High output power: P_{out} = 20 W/channel (Typ.) (V_{CC} = 37 V, R_L = 8 Ω , f = 1 kHz, THD = 10%)
- Low noise: V_{no} = 0.14 mVrms (Typ.) (V_{CC} = 37 V, R_L = 8 Ω , G_V = 34dB, R_g = 10 k Ω , BW = 20 Hz~20 kHz)
- Very few external parts.
- Built in audio muting circuit.
- Built in thermal shut down protector circuit.
- Built in output shifted to GND protection circuit. (AC short)
- Available for using same PCB layout with: TA8200AH, TA8211AH, TA8216H
- Operation supply voltage range (Ta = 25°C)
 - : VCC (opr) = 15~42 V



Weight: 4.04 g (typ.)

Block Diagram



Application Information

1. Voltage gain

The closed loop voltage gain is determined by R_1 , R_2 .

$$\begin{split} \mathrm{G}_V = & 20 \mathrm{log} \, \frac{\mathrm{R}_1 + \mathrm{R}_2}{\mathrm{R}_2} (\mathrm{dB}) \\ = & 20 \mathrm{log} \, \frac{20 \, \mathrm{k}\Omega + 400 \, \Omega}{400 \, \Omega} \\ = & 34 \, \left(\mathrm{dB}\right) \end{split}$$

$$\begin{split} G_V &= 20 \text{log}\, \frac{R_1+R_2+R_3}{R_2+R_3} (\text{dB}) \\ When &\; R_3 = 220 \; \Omega \\ G_V &\simeq 30 \; (\text{dB}) \\ \text{is given.} \end{split}$$

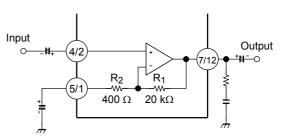
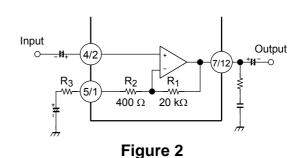


Figure 1



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2. Muting

This product has an excellent muting system.

(1) Audio muting

This IC is possible to make audio muting operation by using 11 pin muting terminal.

Figure 3 shows the equivalent circuit in the muting circuit.

By reducing the voltage of 11 pin to 2.8 V or less, Q₁ will be ON.

Also the base voltage of Q_2 in the differential circuit that has Q_2 and Q_3 will be down.

When Q2 is OFF, I2 and I5 dummy circuits will be operated, and it will shut down the input.

However, the bias circuit is operating after muting, and it takes power supply current at no signal.

8 pin is the capacitor terminal for reducing the pop noise, and it can make the time constant longer by inserting the capacitor externary. If 11 pin is not used, connect 11 pin and 8 pin, then set the voltage abode 4 V.

(2) IC internal muting at VCC OFF

When $V_{CC} = 8 \text{ V}$ or less at V_{CC} off, the detection circuit at V_{CC} off is operated. And the base voltage of Q_1 is reduced and the muting is operated in I_{CC} .

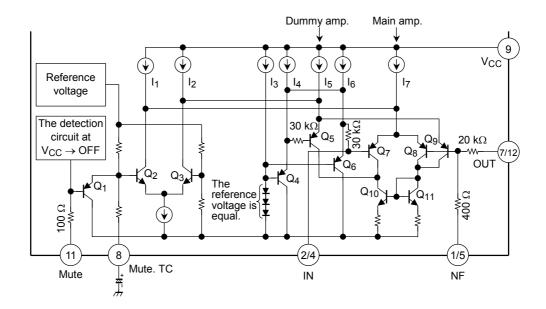


Figure 3

3. The Mounting Place of an Integrated Circuit

This IC cannot withstand the strong electromagnetic fields generated by a CRT. These are likely to cause the device to exhibit malfunctions such as leakage.

Please ensure that the IC is kept away from CRT.

4. Preventive Measures Against Oscillation

To prevent oscillation, it is advisable to use capacitors made of polyester film, which have low temperature and frequency fluctuation daracteristics, as C.

The resistance R in series with C performs phase correction at high frequencies and improves the oscillation allowance.

- (1) Capacitor rating and type
- (2) PCB layout

Note 1: Since the oscillation allowance varies according to the PCB layout, it is recommended that a standard Toshiba PCB be used as a reference for design.

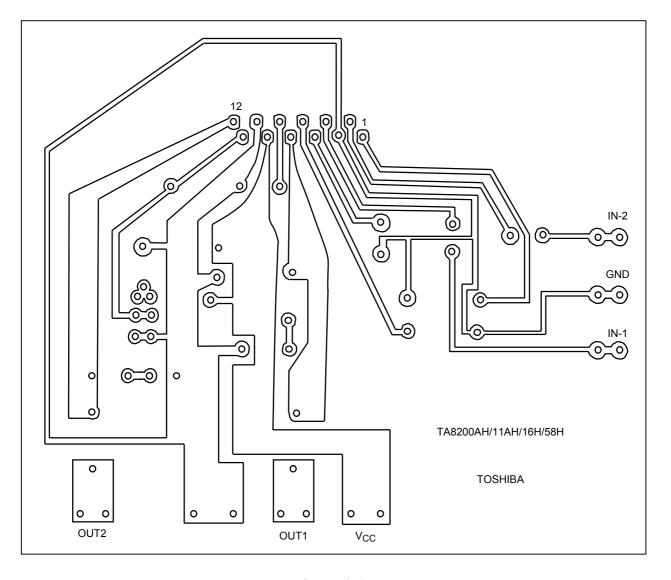
5. Heat-sink

Be aware of the heat-sink capacity.
Use a heat-sink that has high heat conduction.

Note 2: Please connected a Heat-sink to GND potential, otherwise THD may deteriorate.

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Standard PCB



(bottom view)

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Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|-------------------------|---------|------|--|
| Supply voltage | V _{CC} | 50 | V | |
| Output current (Peak/ch) | I _{O (peak)} | 3.5 | Α | |
| Power dissipation | P _D (Note 3) | 25 | W | |
| Operation temperature | T _{opr} | -20~75 | °C | |
| Storage temperature | T _{stg} | -55~150 | °C | |

Note 3: Derated above $Ta = 25^{\circ}C$ in the proportion of 200 mW/°C.

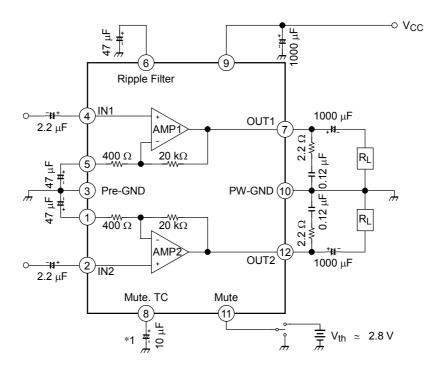
Electrical Characteristics (unless otherwise specified V_{CC} = 37 V, R_L = 8 Ω , R_g = 600 Ω , f = 1 kHz, Ta = 25°C)

| Characteristics | Symbol | Test Circuit | Test Condition | | Тур. | Max | Unit |
|---------------------------|----------------------|-----------------|--|------|------|------|-------|
| Quiescent current | I _{CCQ} | _ | $V_{in} = 0$ | _ | 75 | 130 | mA |
| Output power | P _{out} (1) | _ | THD = 10% | 17 | 20 | _ | · w |
| Cutput power | P _{out} (2) | _ | THD = 1% | _ | 15 | _ | |
| Total harmonic distortion | THD | _ | P _{out} = 2 W | _ | 0.05 | 0.2 | % |
| Voltage gain | G _V | _ | V _{out} = 0.775 Vrms (0dBm) | 32.5 | 34.0 | 35.5 | dB |
| Input resistance | R _{IN} | _ | _ | _ | 30 | _ | kΩ |
| Ripple rejection ratio | R.R. | _ | f _{ripple} = 100 Hz V _{ripple} = 0.775 Vrms (0dBm) | -48 | -60 | _ | dB |
| Output noise voltage | V _{no} | _ | $Rg = 10 \text{ k}\Omega$, $BW = 20 \text{ Hz} \sim 20 \text{ kHz}$ | _ | 0.14 | 0.3 | mVrms |
| Cross talk | C.T. | _ | $\label{eq:region_region} \begin{split} Rg &= 10 \text{ k}\Omega, \\ V_{out} &= 0.775 \text{ Vrms (0dBm)} \end{split}$ | -50 | -60 | _ | dB |
| Mute on voltage | Mute-on | _ | Mute on | GND | _ | 1.4 | V |
| Mute off voltage | Mute-off | _ | Mute off | 3.7 | _ | 10 | V |
| Mute ATT | ATT | _ | $V_{out} = 0.775 \text{ Vrms} \rightarrow \text{Mute}$ | -50 | -60 | | dB |

Typ. DC Voltage of Each Terminal ($V_{CC} = 28 \text{ V}$, $Ta = 25^{\circ}\text{C}$)

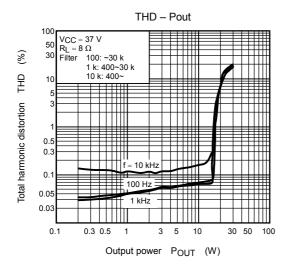
| Terminal No. | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 |
|----------------|-----|-----|-----|-----|-----|------|------|-----|----------|-----|-----|------|
| DC voltage (V) | 2.5 | 2.8 | GND | 2.8 | 2.5 | 12.5 | 19.4 | 5.1 | V_{CC} | GND | 4.8 | 19.4 |

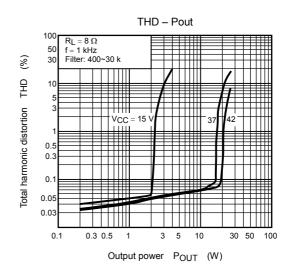
Test Circuit

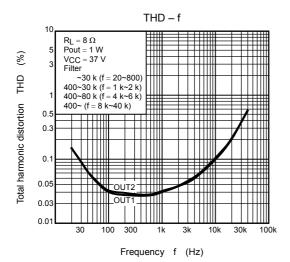


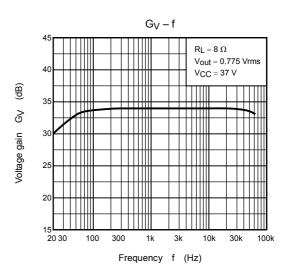
*1: The capacitor for reducing POP noise at mute ON.

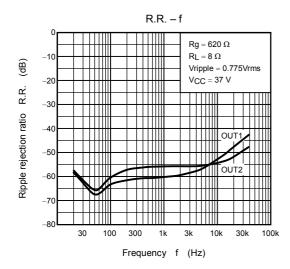
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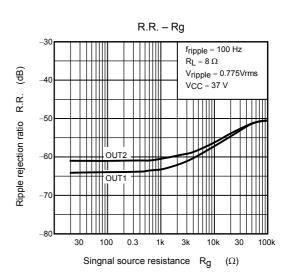


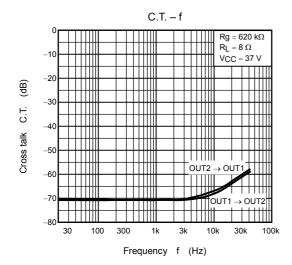


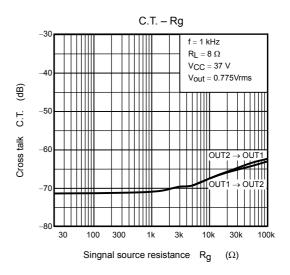


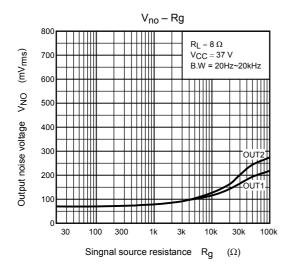


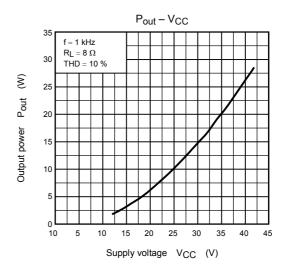


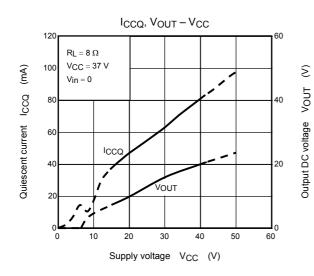


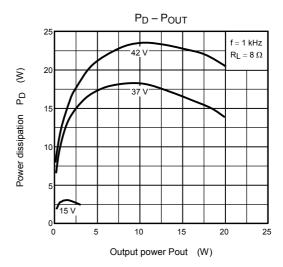




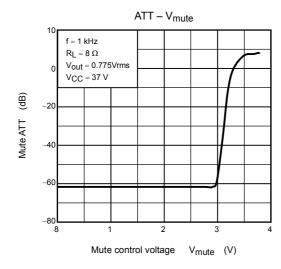


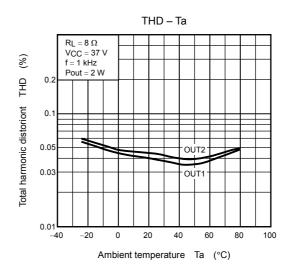


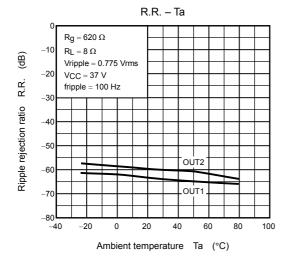


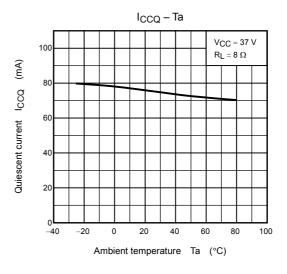


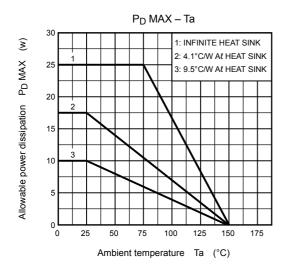
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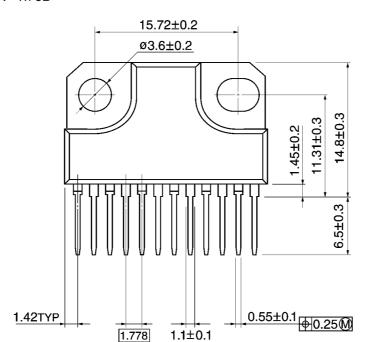


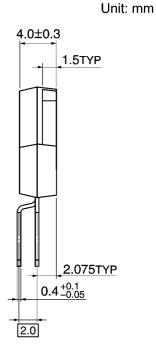


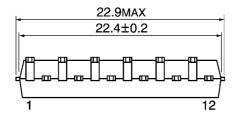


Package Dimensions

HZIP12-P-1.78B







Weight: 4.04 g (typ.)

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